Power MOSFET

7.0 A, 20 V, Common Drain, Dual N-Channel, TSSOP-8

Features

- Low R_{DS(on)}
- Higher Efficiency Extending Battery Life
- Logic Level Gate Drive
- 3 mm Wide TSSOP-8 Surface Mount Package
- High Speed, Soft Recovery Diode
- TSSOP-8 Mounting Information Provided
- Pb-Free Package is Available

Applications

• Battery Protection Circuits

MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	20	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	±12	Vdc
Drain Current - Continuous @ T _A 25°C (Note 1) - Continuous @ T _A 70°C (Note 1) - Pulsed (Note 3)	I _D I _D I _{DM}	7.0 5.6 20	Adc
Total Power Dissipation @ T _A 25°C (Note 1)	P _D	1.81	W
Drain Current - Continuous @ T _A 25°C (Note 2) - Continuous @ T _A 70°C (Note 2) - Pulsed (Note 3)	I _D I _D	6.2 4.9 18	Adc
Total Power Dissipation @ T _A 25°C (Note 2)	P _D	1.39	W
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to +150	ç
Thermal Resistance – Junction–to–Ambient (Note 1) Junction–to–Ambient (Note 2)	$R_{\theta JA}$	69 90	°C/W
Maximum Lead Temperature for Soldering Purposes for 10 seconds	TL	260	ç

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

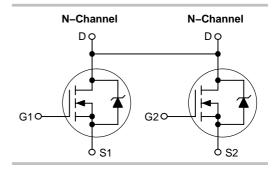
- Mounted onto a 2" square FR-4 Board (1 in sq, 2 oz. Cu 0.06" thick single sided), t ≤ 10 sec.
- 2. Mounted onto a 2" square FR-4 Board (1 in sq, 2 oz. Cu 0.06" thick single sided), Steady State.
- 3. Pulse Test: Pulse Width = 300 μ s, Duty Cycle = 2%.



ON Semiconductor®

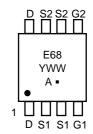
http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
20 V	17 mΩ @ 4.5 V	7.0 A



MARKING DIAGRAM & PIN ASSIGNMENT





E68 = Specific Device Code A = Assembly Location

Y = Year

WW = Work Week
= Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
NTQD6968N	TSSOP-8	100 Units / Rail
NTQD6968NR2	TSSOP-8	4000/Tape & Reel
NTQD6968NR2G	TSSOP-8 (Pb-Free)	4000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)

	aracteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltag (V _{GS} = 0 Vdc, I _D = 250 μAdc) Temperature Coefficient (Positive)	e	V _{(BR)DSS}	20	_ 16	- -	Vdc mV/°C
Zero Gate Voltage Collector Current $(V_{DS} = 16 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_{J} $ $(V_{DS} = 16 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_{J}$	= 25°C)	I _{DSS}	- -	- -	1.0 10	μAdc
Gate-Body Leakage Current (V _{GS} = ±12 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	_	±100	nAdc
ON CHARACTERISTICS						
$\label{eq:GateThreshold Voltage} Gate Threshold Voltage \\ (V_{DS} = V_{GS}, I_D = 250 \ \mu Adc) \\ Temperature Coefficient (Negative)$		V _{GS(th)}	0.6	0.75 3.0	1.2	Vdc mV/°C
Static Drain-to-Source On-State R ($V_{GS} = 4.5 \text{ Vdc}$, $I_D = 7.0 \text{ Adc}$) ($V_{GS} = 2.5 \text{ Vdc}$, $I_D = 7.0 \text{ Adc}$) ($V_{GS} = 2.5 \text{ Vdc}$, $I_D = 3.5 \text{ Adc}$)	esistance	R _{DS(on)}	- - -	0.017 0.022 0.022	0.022 0.030 0.030	Ω
Forward Transconductance (V _{DS} =	10 Vdc, I _D = 7.0 Adc)	9FS	_	19.2	-	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	_	630	_	pF
Output Capacitance	$(V_{DS} = 16 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{oss}	-	260	-	
Transfer Capacitance	,	C _{rss}	-	95	-	
SWITCHING CHARACTERISTICS	(Notes 4 and 5)					
Turn-On Delay Time		t _{d(on)}	-	8.0	_	ns
Rise Time	$(V_{DD} = 16 \text{ Vdc}, I_D = 7.0 \text{ Adc},$	t _r	-	25	_	
Turn-Off Delay Time	$V_{GS} = 4.5 \text{ Vdc}, R_G = 6.0 \Omega)$	t _{d(off)}	-	60	_	
Fall Time		t _f	-	65	_	
Gate Charge	(V _{DS} = 16 Vdc,	Q _{tot}	_	12.5	17	nC
	$V_{GS} = 4.5 \text{ Vdc},$ $I_{D} = 7.0 \text{ Adc})$	Q_{gs}	-	1.0	_	
	ID = 1.0 Adc)	Q_{gd}	_	5.0	_	
BODY-DRAIN DIODE RATINGS (N	lote 4)					
Forward On-Voltage	$(I_S = 7.0 \text{ Adc}, V_{GS} = 0 \text{ Vdc})$	V_{SD}	-	0.82	1.2	Vdc
Reverse Recovery Time		t _{rr}	_	35	-	ns
	$(I_S = 7.0 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, \\ dI_S/dt = 100 \text{ A/}\mu\text{s})$	ta	_	15	-	
	<u>-</u>	t _b	_	20	-	
Reverse Recovery Stored Charge		Q_{RR}	-	0.02	-	μС

Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%.
 Switching characteristics are independent of operating junction temperature.

 $V_{DS} \ge 10 \text{ V}$

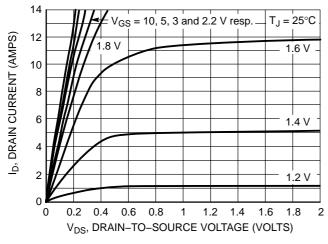
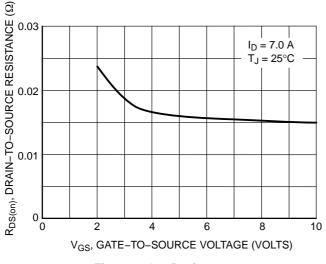


Figure 1. On-Region Characteristics

Figure 2. Transfer Characteristics



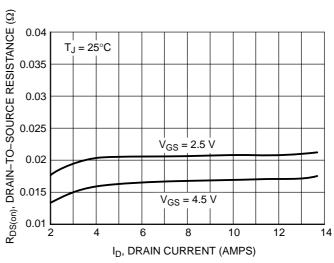
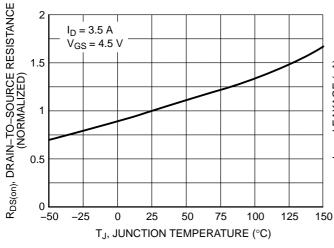


Figure 3. On–Resistance versus Gate–to–Source Voltage

Figure 4. On-Resistance versus Drain Current and Gate Voltage



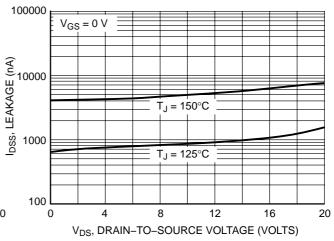
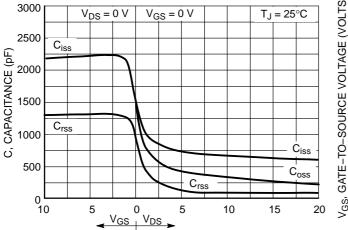


Figure 5. On–Resistance Variation with Temperature

Figure 6. Drain-to-Source Leakage Current versus Voltage



GATE-TO-SOURCE OR DRAIN-TO-SOURCE VOLTAGE (VOLTS)



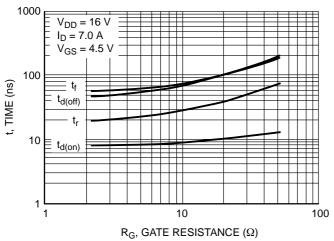


Figure 9. Resistive Switching Time Variation versus Gate Resistance

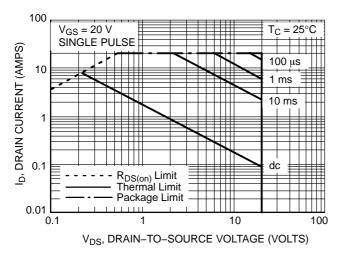


Figure 11. Maximum Rated Forward Biased Safe Operating Area

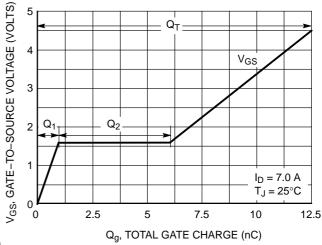


Figure 8. Gate-to-Source Voltage versus Total Charge

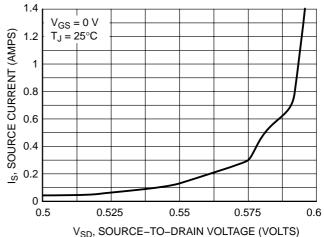


Figure 10. Diode Forward Voltage versus Current

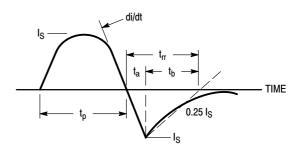


Figure 12. Diode Reverse Recovery Waveform

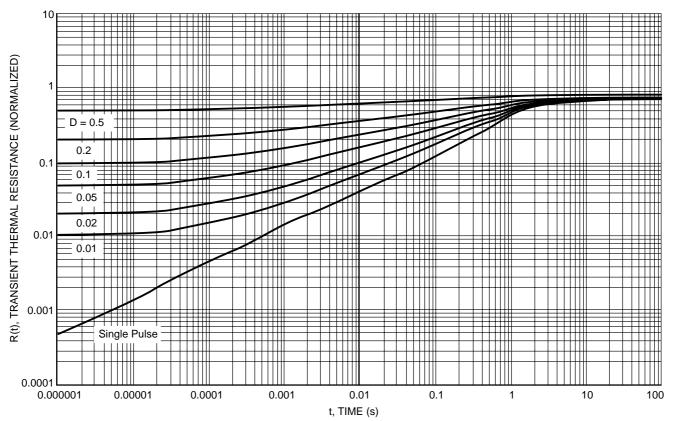


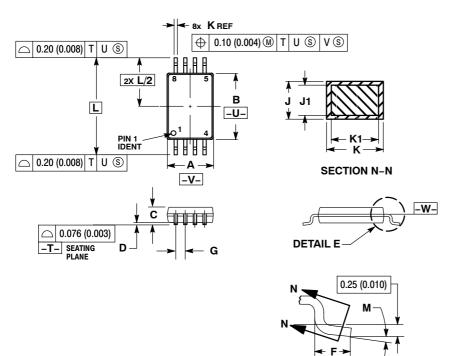
Figure 13. Thermal Response





TSSOP-8 CASE 948S-01 ISSUE C

DATE 20 JUN 2008



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH.
 PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- (0.006) PEH SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE
- 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	4.30	4.50	0.169	0.177
С		1.10		0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.70	0.020	0.028
G	0.65	BSC	0.026 BSC	
7	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	0°	8°	0°	8°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code = Assembly Location Α

= Year WW = Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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